

## Non-CO<sub>2</sub> Greenhouse Gases: High-GWP Gases

**Source/Sectors:** Semiconductor Sector

**Technology:** CVD cleaning emission reduction/NF<sub>3</sub> remote clean (C.3.1)

### Description of the Technology:

The Novellus's *In-situ* NF<sub>3</sub> Clean Technology system introduces NF<sub>3</sub> directly into the CVD process chamber where the gas is dissociated in plasma. NF<sub>3</sub> possesses a high GWP very close to that of C<sub>2</sub>F<sub>6</sub>, however, the chemical's overall high efficiency leads to the reduction of gas emissions and thus, less climate impact as compared to C<sub>2</sub>F<sub>6</sub> (US Climate Change, 2005).

The NF<sub>3</sub> Remote Clean™ Technology developed by Applied Materials uses an upstream (remote) device to dissociate NF<sub>3</sub> using argon gas at a 99% efficiency rate. In addition, chamber cleaning times are 30 to 50% faster than baseline C<sub>2</sub>F<sub>6</sub> clean times. The system converts the source gas to active N and F atoms in the plasma, upstream of the process chamber. These electrically neutral atoms can selectively remove material in the chamber. The remote cleaning technology differs from *in situ* technology in that the NF<sub>3</sub> dissociates into plasma before entering the chamber rather than being dissociated inside the chamber. The byproducts of Remote Clean™ include HF, F<sub>2</sub>, and other gases, of which all but F<sub>2</sub> are removed by facility acid scrubber systems (US Climate Change, 2005).

**Effectiveness:** Good

**Implementability:** All fabrication facilities

**Reliability:** Good

**Maturity:** Good.

**Environmental Benefits:** High-GWP gas emission reduction

### Cost Effectiveness:

Technology	Lifetime (yrs)	MP (%)	RE (%)	TA (%)	Capital cost	Annual cost	Benefits
CVD cleaning emission reduction – NF <sub>3</sub> remote clean <sup>1</sup>	5	90	90	60	\$90.76	\$0.00	\$0.00

Note: MP: market penetration; RE: reduction efficiency; TA: technical applicability; costs are in year 2000 US\$/MT<sub>CO<sub>2</sub>-Eq.</sub>

1: CEC (2005) & USEPA (2001)

**Industry Acceptance Level:** NF<sub>3</sub> use is rapidly gaining market share in the semiconductor industry for CVD chamber cleaning because of its high process efficiency.

**Limitations:** This option is only applicable to control emissions from chamber cleaning processes; it accounts for approximately 70% of total fabrication emissions (IEA, 2003).

### Sources of Information:

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